## Received: 10-22-2003

## **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

METHOD AND MANUFACTURE OF THIN SILICON ON INSULATOR (SOI) WITH RECESSED CHANNEL AND DEVICES MANUFACTURED THEREBY

**Application Number:** 

10/605,726

Confirmation Number:

First Named Applicant:

Huilong Zhu

Attorney Docket Number:

FIS920030303US1

Art Unit:

2813

Examiner:

Search string:

( 6465311 or 6391720 or 6225173 or 4616400 or 5814544 ).pn

## **US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

	init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
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## **Signature**

Examiner Name	Date			
Han. 11	February 4, 2005			
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